

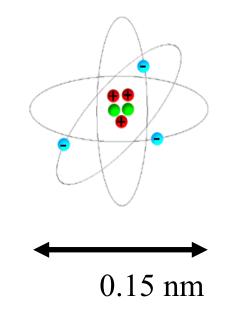
Technische Universität Graz

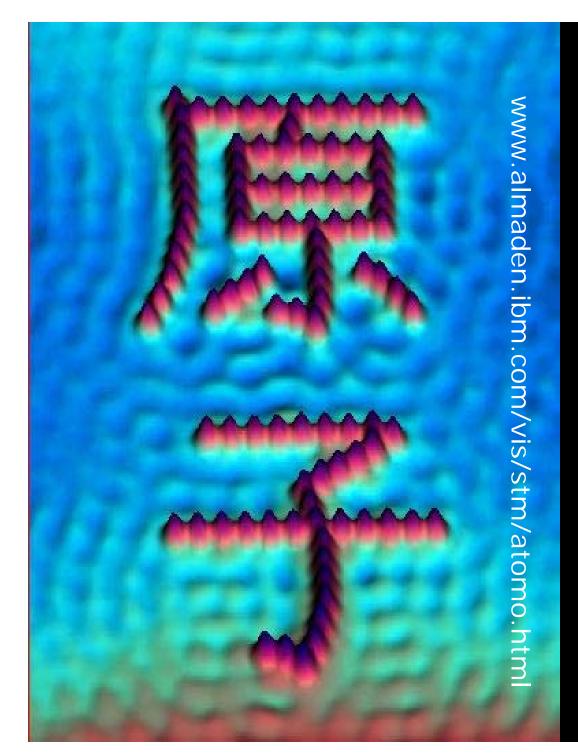
Institute of Solid State Physics

Electrons in Crystals

Electrons

Charge = $-1.6022 \times 10^{-19} \text{ C}$ Mass = $9.11 \times 10^{-31} \text{ kg}$ Radius = ?





Quantum Mechanics

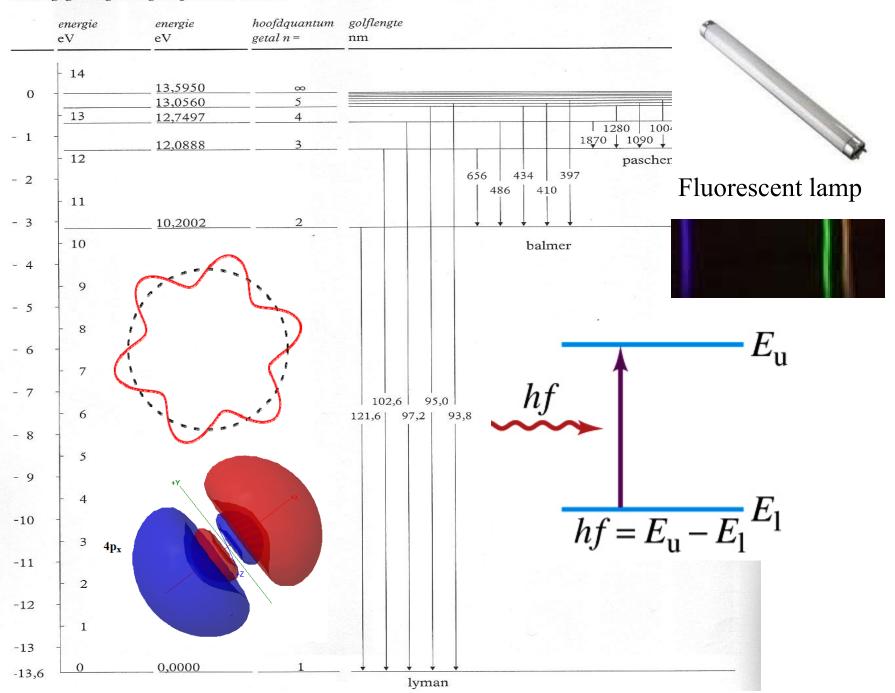
Everything moves like a wave but exchanges energy and momentum like a particle.

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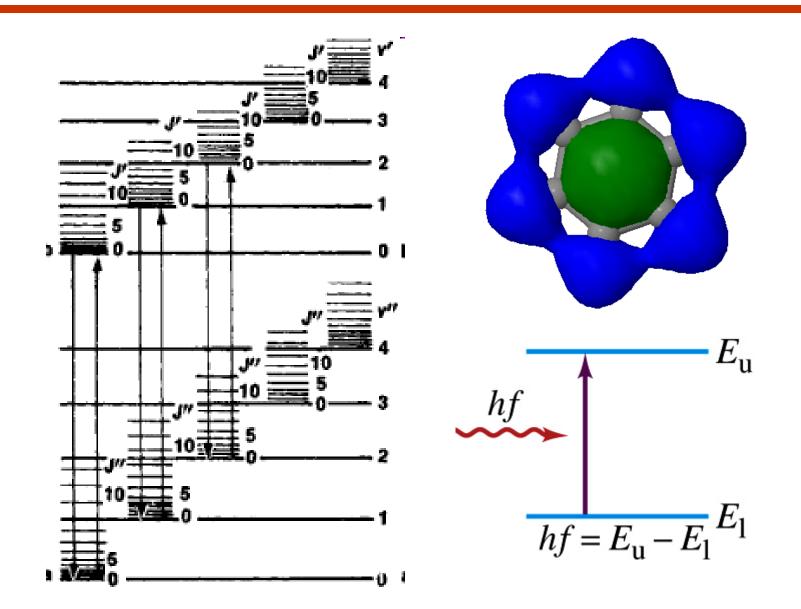




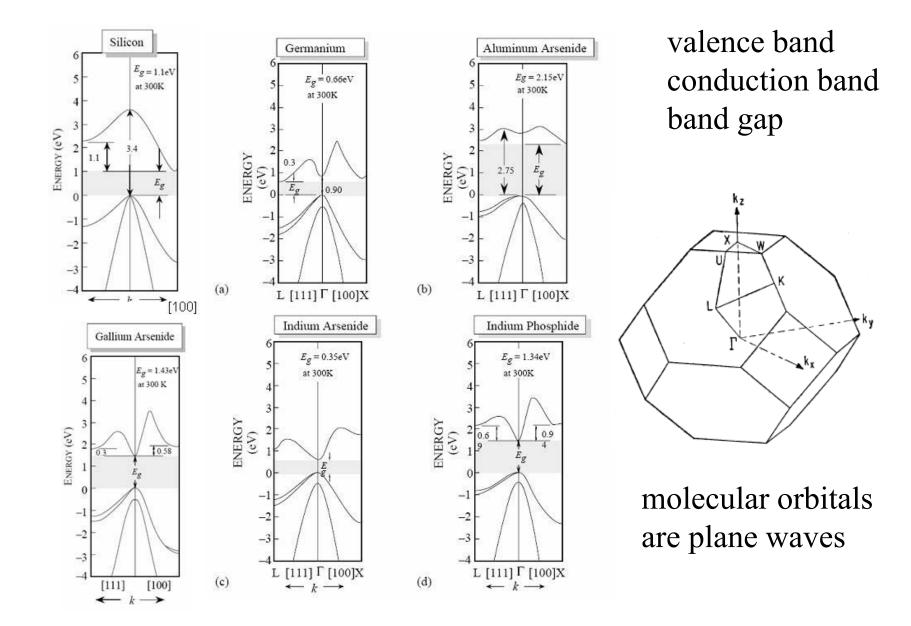
de aangegeven golflengten gelden in vacuüm



Molecular energy levels



Semiconductors



wave vector k

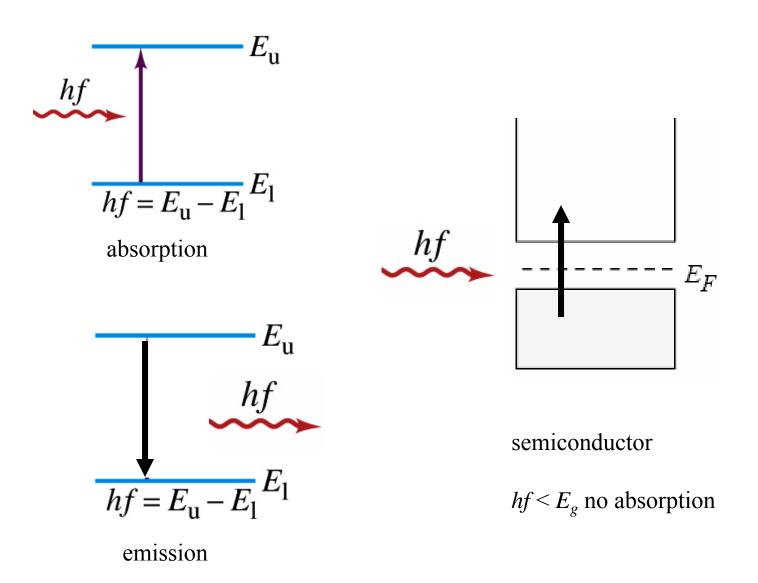
A *k*-vector points in the direction a wave is propagating.

wavelength:

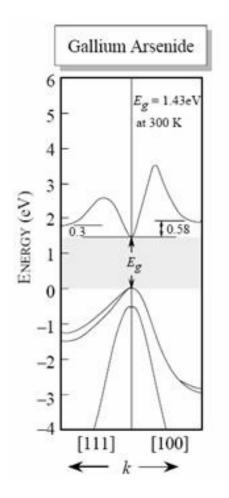
$$\lambda = \frac{2\pi}{\left|\vec{k}\right|}$$

momentum:
$$\vec{p} = \hbar \vec{k}$$

Absorption and emission of photons



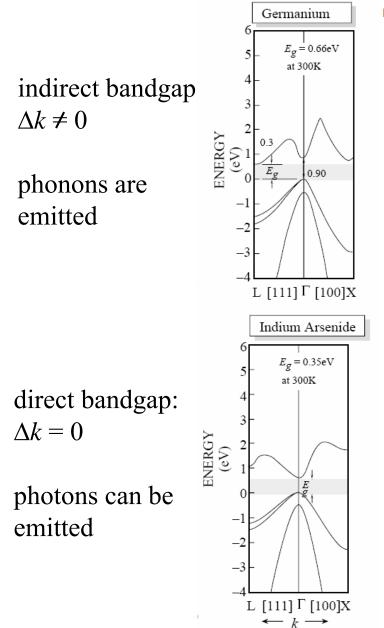
What color light does a GaAs LED emit?



$$E = 1.6022 \times 10^{-19} \times 1.43 \text{ J} = hf = \frac{hc}{\lambda}$$

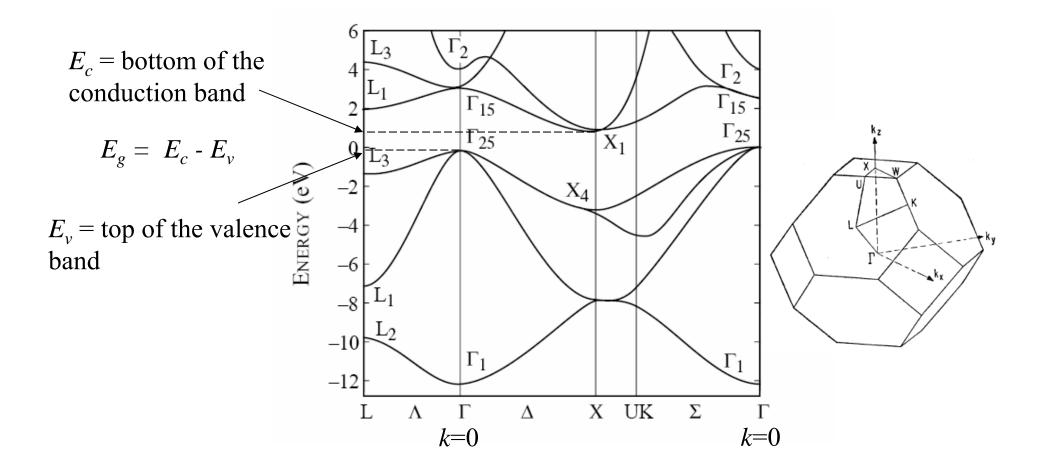
 $\lambda = 867 \text{ nm}$ infrared

Direct and indirect band gaps



Momentum must be conserved when photons are absorbed or emitted.

Silicon band structure

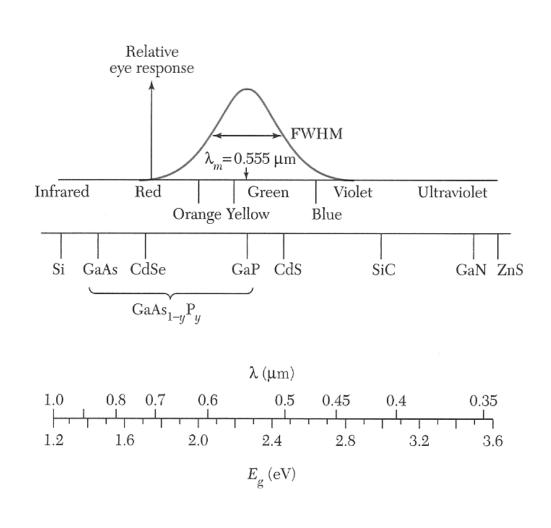


Electrons with energies in the gap are reflected out of the crystal.

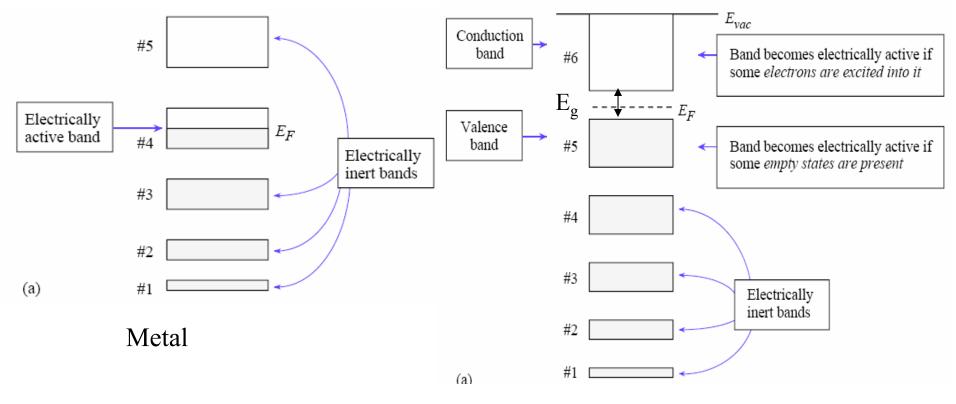
Material	Wavelength (nm)
InAsSbP/InAs	4200
InAs	3800
GaInAsP/GaSb	2000
GaSb	1800
$Ga_x In_{1-x} As_{1-y} P_y$	1100-1600
Ga _{0.47} In _{0.53} As	1550
Ga _{0.27} In _{0.73} As _{0.63} P _{0.37}	1300
GaAs:Er,InP:Er	1540
Si:C	1300
GaAs:Yb,InP:Yb	1000
Al _x Ga _{1-x} As:Si	650-940
GaAs:Si	940
Al _{0.11} Ga _{0.89} As:Si	830
Al _{0.4} Ga _{0.6} As:Si	650
$GaAs_{0.6}P_{0.4}$	660
$GaAs_{0.4}P_{0.6}$	620
$GaAs_{0.15}P_{0.85}$	590
$(Al_xGa_{1-x})_{0.5}In_{0.5}P$	655
GaP	690
GaP:N	550-570
$Ga_{x}In_{1-x}N$	340,430,590
SiC	400-460
BN	260,310,490

TABLE 1Common III-V materials used to produceLEDs and their emission wavelengths.

Light emitting diodes



Metals, semiconductors, insulators

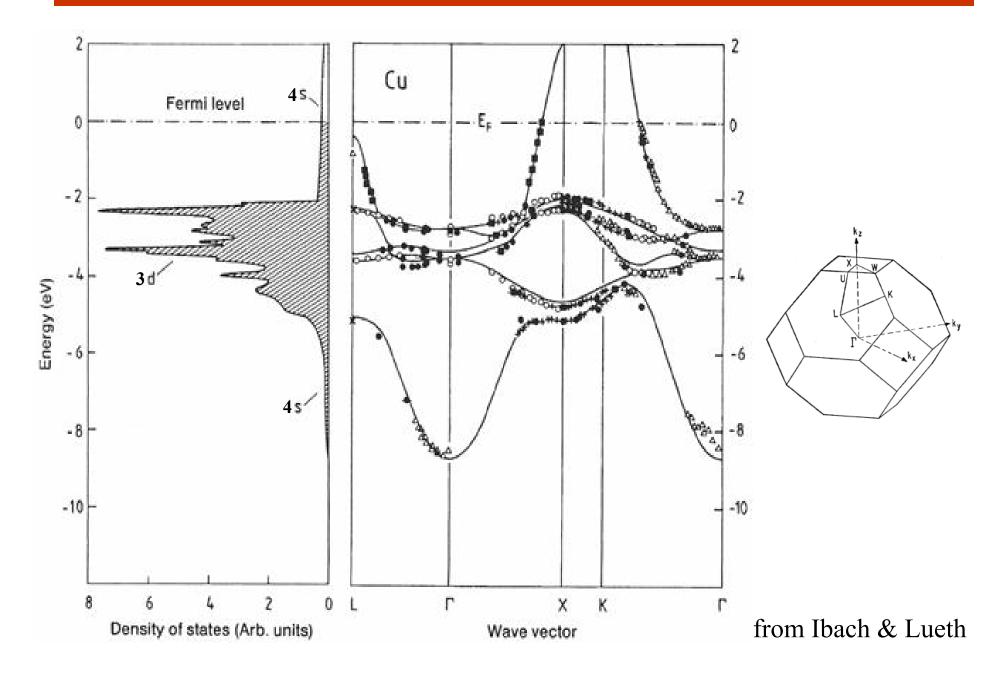


Semiconductor or insulator

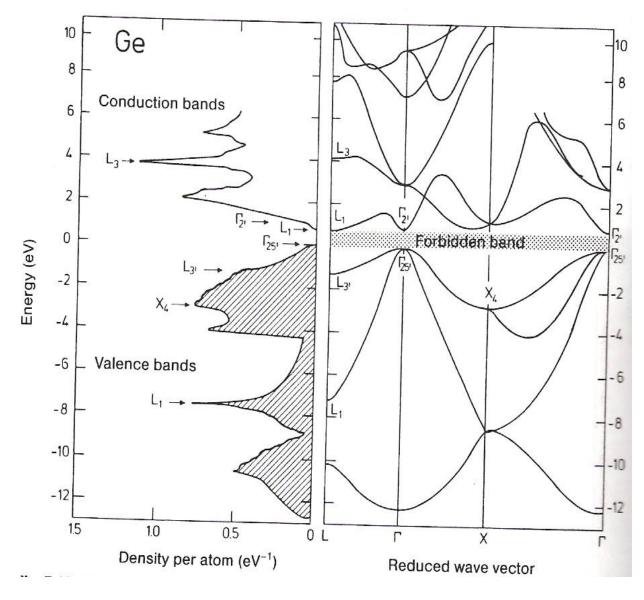
 $E_g < 3eV = Semiconductor$ $E_g > 3eV = Insulator$

from: Singh

Copper dispersion relation and density of states



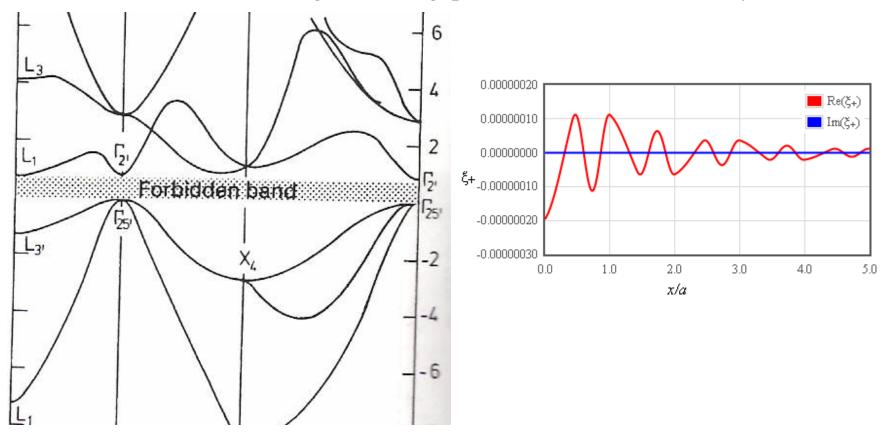
Germanium



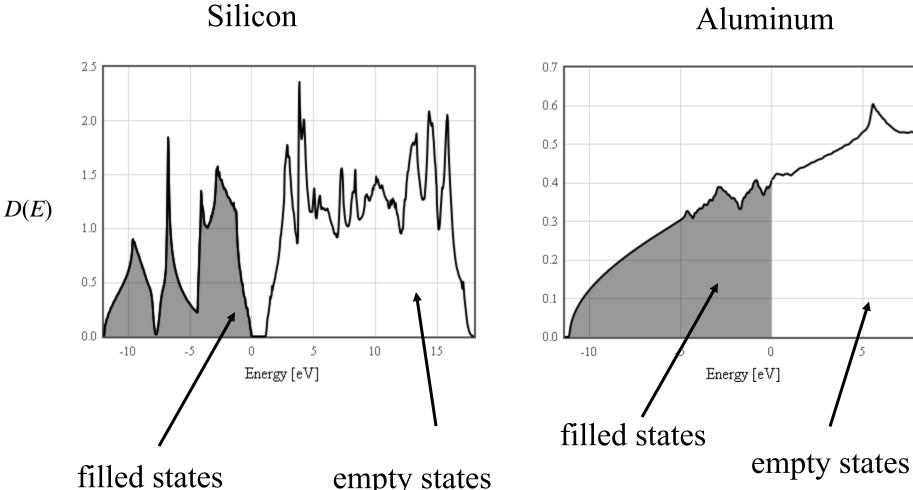
from Ibach & Lueth

Band gap

Electrons with energies in the gap are reflected out of the crystal.

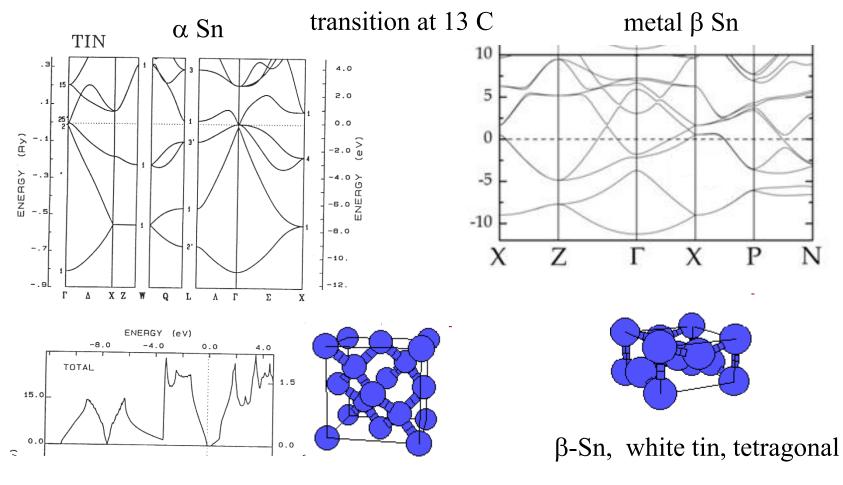


Density of states



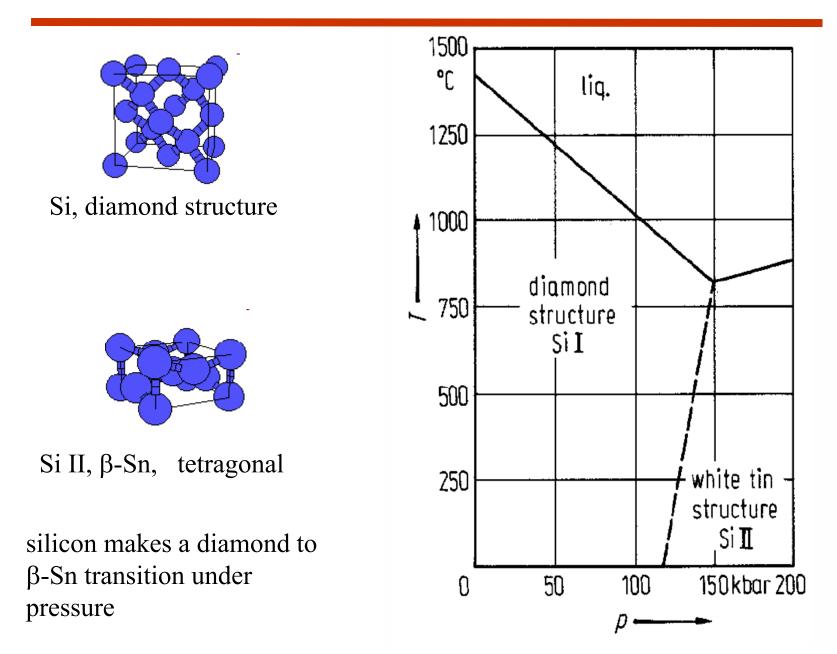
empty states

Structural phase transition in Sn



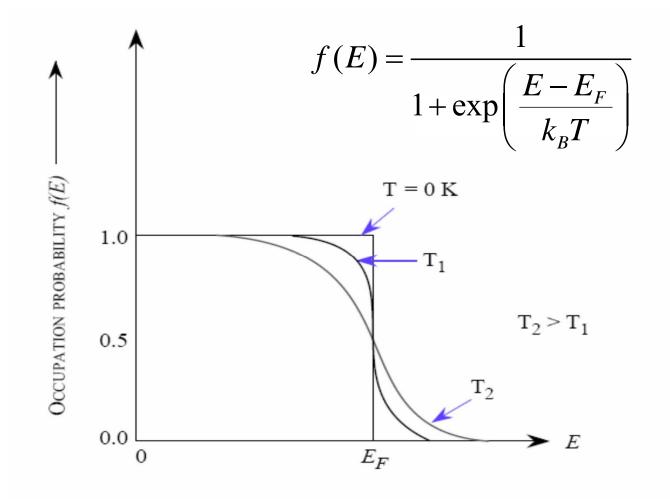
 α -Sn, gray tin, diamond structure

Structural phase transitions



Fermi function

f(E) is the probability that a state at energy E is occupied.



Silicon density of states

